PATENT ASSIGNMENT

Electronic Version v1.1 Stylesheet Version v1.1

SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT
EFFECTIVE DATE:	07/24/2007

CONVEYING PARTY DATA

Name	Execution Date
The Regents of the University of California	06/27/2007

RECEIVING PARTY DATA

Name:	Japan Science and Technology Agency
Street Address:	4-1-8, Honcho
City:	Kawaguchi City, Saitama Prefecture
State/Country:	JAPAN
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PROPERTY NUMBERS Total: 2

Property Type	Number
PCT Number:	US0621128
Application Number:	11444946

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Total Attachments: 1

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PATENT

REEL: 019604 FRAME: 0289

<u>ASSIGNMENT</u>

U.C. Case No. 2005-668

G & C Case No. 30794.140-WO/US-U1

For good and valuable consideration, the receipt of which is hereby acknowledged, ASSIGNOR, THE REGENTS OF THE UNIVERSITY OF CALIFORNIA, hereby sells, assigns and transfers to ASSIGNEE, JAPAN SCIENCE AND TECHNOLOGY AGENCY, a statutory corporation of the Japanese government, having its principal offices located at 4-1-8, Honcho, Kawaguchi City, Saitama Prefecture, 332-0012, Japan, and the successors, assigns and legal representatives of the ASSIGNEE, an undivided one-half (1/2) or fifty percent (50%) interest in and to the following patent applications:

PCT patent application no. PCT/US2006/021128, filed on June 1, 2006, by Robert M. Farrell Jr., Troy J. Baker, Arpan Chakraborty, Benjamin A. Haskell, P. Morgan Pattison, Rajat Sharma, Umesh Kumar Mishra, Steven P. DenBaars, James S. Speck, and Shuji Nakamura, and entitled TECHNIQUE FOR THE GROWTH AND FABRICATION OF SEMIPOLAR (Ga,Al,In,B)N THIN FILMS, HETEROSTRUCTURES, AND DEVICES; and

U.S. patent application serial No. 11/444,946, filed on June 1, 2006, by Robert M. Farrell Jr., Troy J. Baker, Arpan Chakraborty, Benjamin A. Haskell, P. Morgan Pattison, Rajat Sharma, Umesh Kumar Mishra, Steven P. DenBaars, James S. Speck, and Shuji Nakamura, and entitled TECHNIQUE FOR THE GROWTH AND FABRICATION OF SEMIPOLAR (Ga,Al,In,B)N THIN FILMS, HETEROSTRUCTURES, AND DEVICES;

and any legal equivalent thereof in any country, including the right to claim priority and, in and to, all Letters Patent to be obtained therefor, and any continuation, division, continuation-in-part, extension, conversion to 35 U.S.C. §111(a) or substitute thereof, and any reissue, reexamination or extension of said Letters Patent and all rights under all International Conventions for the Protection of Industrial Property;

Executed this 21 day of

Title: Manager, Patent Prosecution University of California

Office of Technology Transfer

assign.doc

RECORDED: 07/24/2007

PATENT REEL: 019604 FRAME: 0290